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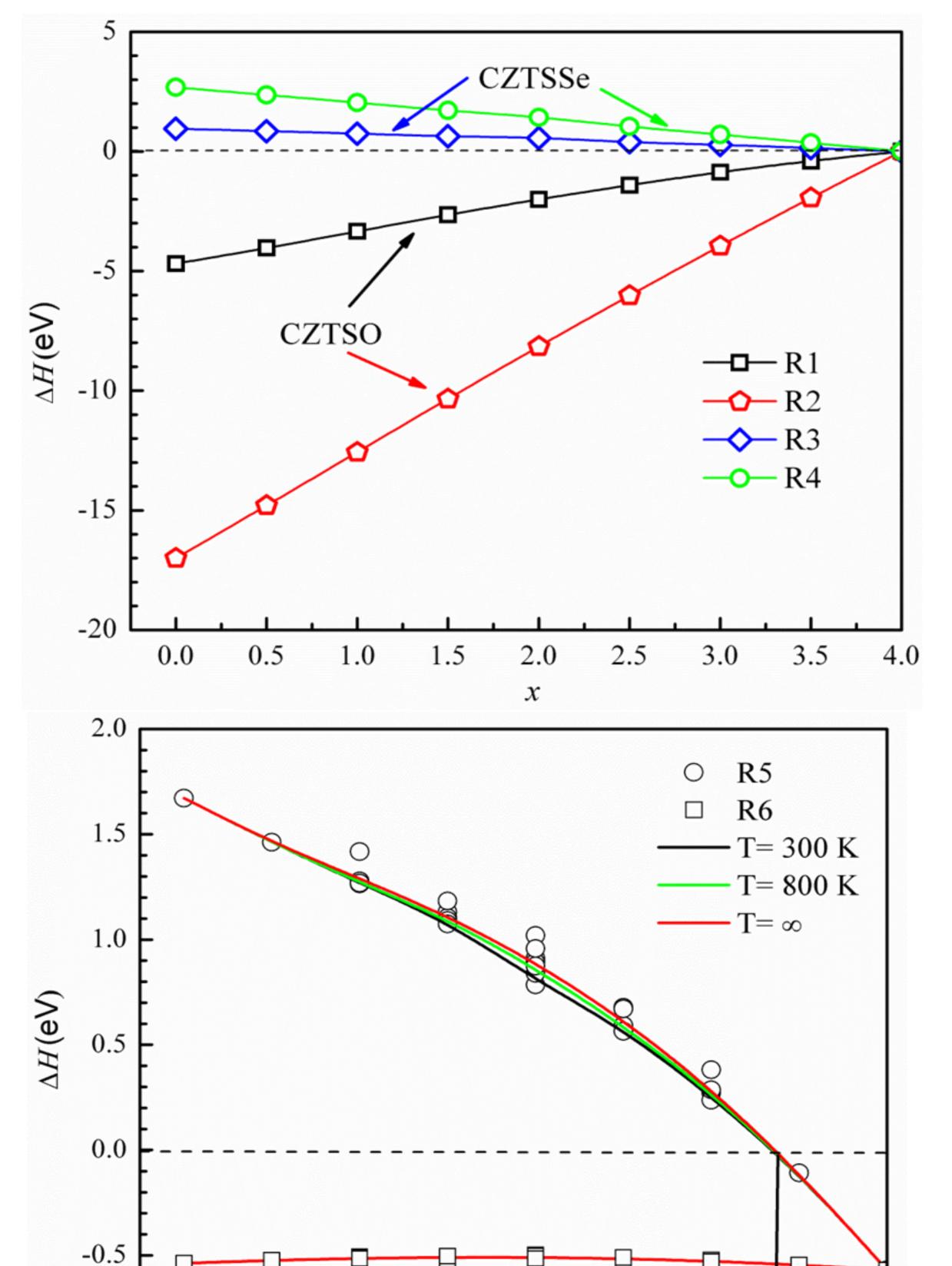
First principles simulations of Cu₂ZnSnS_xO_{4-x} alloys

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Abstract

Crystalline Cu₂ZnSnS₄ (CZTS) has been well studied for its photovoltaic properties. This poster reports a systematic computational study of CZTS alloys with oxygen substituting for S in the form Cu₂ZnSnS_xO_{4-x}, in order to understand their stability and structural properties. The calculations find Cu₂ZnSnO₄ (CZTO) to have a welldefined meta-stable kesterite structure with a heat formation of 4.7 eV





lower than that of CZTS. This result is consistent with a near formation of 4.7 eV lower than that of CZTS. This result is consistent with the general observation that CZTS is very reactive when exposed to air. Interestingly, the results find that CZTS is stable with respect to its decomposition products; the calculated enthalpy for CZTS \rightarrow Cu₂S + ZnS + SnS₂ is $\Delta H_{cal} = +0.6$ eV. However, for CZTO the corresponding decomposition is predicted to be exothermic; the calculated enthalpy for CZTO \rightarrow Cu₂O + ZnO + SnO₂ is $\Delta H_{cal} = -1.7$ eV. The simulations of S/O alloys show that there are preferred structures for the O configurations. For example, for alloys with x = 2, the energy difference between the lowest and highest energy O arrangements is 0.25 eV/formula unit.

Results & Discussions

I Values of the heats of formation

From the heats of formation, it is possible to predict the synthesis and decomposition processes for the CZTSO family.

Table I: Summary of heat of formation results for CZTSO and related materials in units of eV per formula unit. * were used to fit the O_2 reference energy.

Formula Unit	ΔH_{col}	AHavn

r or mula Unit	Δ Π cal	Δ Π exp
CuO *	-1.645	-1.630, ^a -1.617, ^b -1.677 ^c
Cu_2O^*	-1.756	-1.747, ^a -1.769, ^b -1.795 ^c
ZnO [*]	-3.410	-3.633 ^a
SnO [*]	-2.949	-2.909 ^a
SnO_2^*	-5.788	-5.987 ^a
CuS	-0.721	-0.550, ^a -0.542 ^c
Cu_2S	-0.931	-0.823, ^a -0.824 ^c
ZnS	-1.774	-1.996, ^a -2.127 ^c
SnS	-1.072	-1.036, ^a -1.118 ^c
SnS_2	-1.320	-1.592 ^c
Sn_2S_3	-2.353	-2.732 ^c
SO_3	-5.089	-4.7 11 ^a
$\operatorname{CuSO_4}^*$	-7.894	-7.995, ^a -7.980 ^b
$ZnSO_4$ *	-10.207	-10.186, ^a -10.171 ^c
Cu_2SnO_3	-5.938	
Cu_2SnS_3	-2.680	
KS-CZTS	-4.596	
KS-CZTO	-9.246	

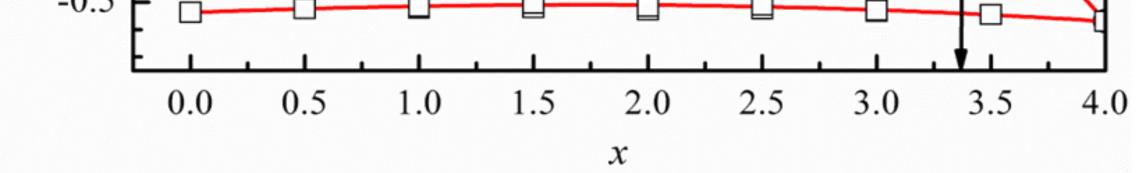
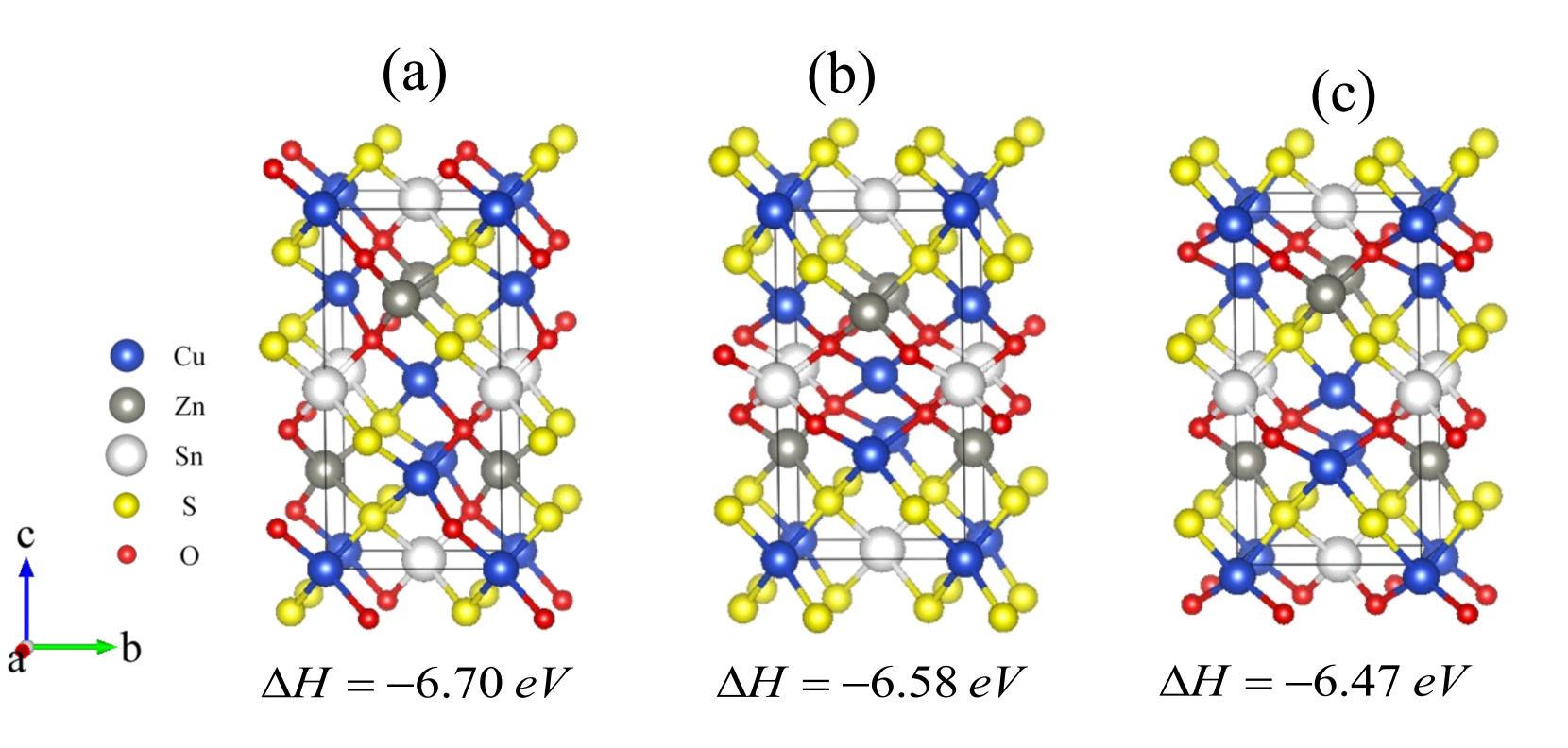


Fig. 1. Calculated reaction energies of *R*1, *R*2, *R*3, *R*4, *R*5 and *R*6 averaged over all alloy configurations and plotted as a function of *x* (the concentration of sulfur).

III Where does the oxygen go?



II Does oxidation occur naturally?

Possible oxidation and selenization reactions that relate the synthesis and decomposition processes for the CZTS family.

- R1: $\operatorname{Cu}_2 \operatorname{ZnSnS}_4 + (4-x)\frac{1}{2}O_2 \rightarrow \operatorname{Cu}_2 \operatorname{ZnSnS}_x O_{4-x} + (4-x)S_{\text{solid}}$
- R2: $Cu_2ZnSnS_4 + (4-x)\frac{3}{2}O_2 \rightarrow Cu_2ZnSnS_xO_{4-x} + (4-x)SO_{2 (gas)}$
- R3: $Cu_2ZnSnS_4 + (4-x)Se_{solid} \rightarrow Cu_2ZnSnS_xSe_{4-x} + (4-x)S_{solid}$
- R4: $Cu_2ZnSnS_4 + (4-x)Se_{gas} \rightarrow Cu_2ZnSnS_xSe_{4-x} + (4-x)S_{gas}$
- R5: $\frac{x}{4}(Cu_{2}S+ZnS+SnS_{2})+(1-\frac{x}{4})(Cu_{2}O+ZnO+SnO_{2}) \rightarrow Cu_{2}ZnSnS_{x}O_{4-x}$ R6: $\frac{x}{4}(Cu_{2}S+ZnS+SnS_{2})+(1-\frac{x}{4})(Cu_{2}Se+ZnSe+SnSe_{2}) \rightarrow Cu_{2}ZnSnS_{x}Se_{4-x}$

Reference

Fig. 2. Ball and stick diagram of the primitive simulation cell for CZTSO alloys with x=2 showing 3 of the 10 unique configurations. (a) structure with lowest energy (b) a high symmetry configuration. (c) structure with the highest energy configuration.

Conclusions

- Oxygen incorporation in the CZTS lattice is energetically favorable.
- $Cu_2ZnSnS_xO_{4-x}$ crystals are stable only for the small range of 3.3 < x < 4.0.
- For CZTSO alloys, O have preferred configurations in which O sites are not concentrated in any a -b plane.
- The energy difference between the highest and lowest energy structures for x=2.0 system is 0.2 eV.

[a] W. M. Haynes, ed., CRC Handbook of Chemistry and Physics, 92th Edition (CRC Press, Taylor & Francis Group, 2011) ISBN 978-1-4398-5511-9.

[b] J. Chase, M. W., C. A. Davies, J. Downey, J. R., D. J. Frurip, R. A. McDonald, and A. N. Syverud, NIST JANAF Thermochemical Tables 1985," (1986), available online: http://kinetic.nist.gov/janaf.

[c] O. Kubaschewski, C. B. Alcock, and P. J. Spencer, Materials Thermochemistry, 6th edition (Pergamon Press, New York, 1993) ISBN 0-08-0418899. The 5th edition text was also used.